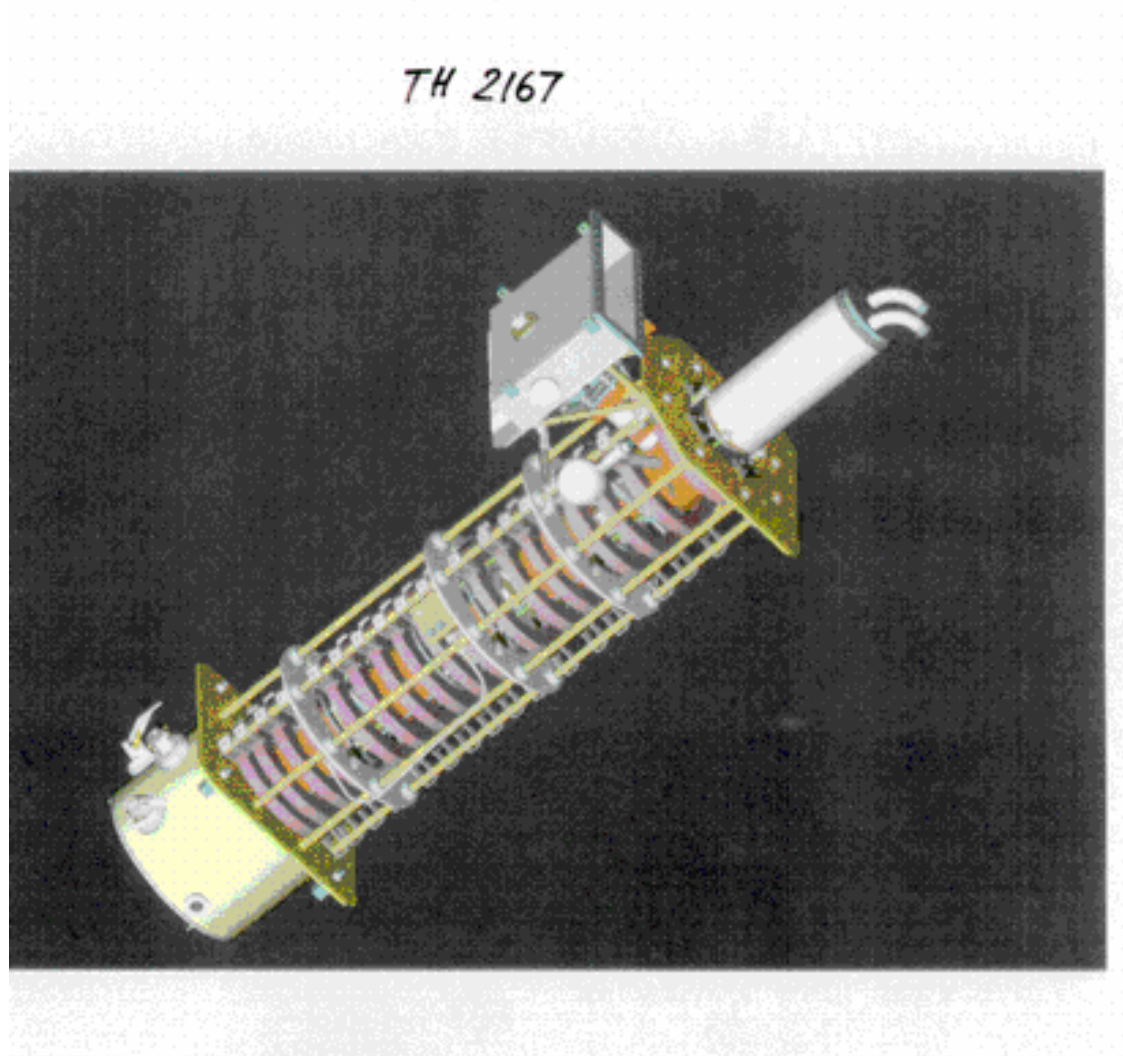


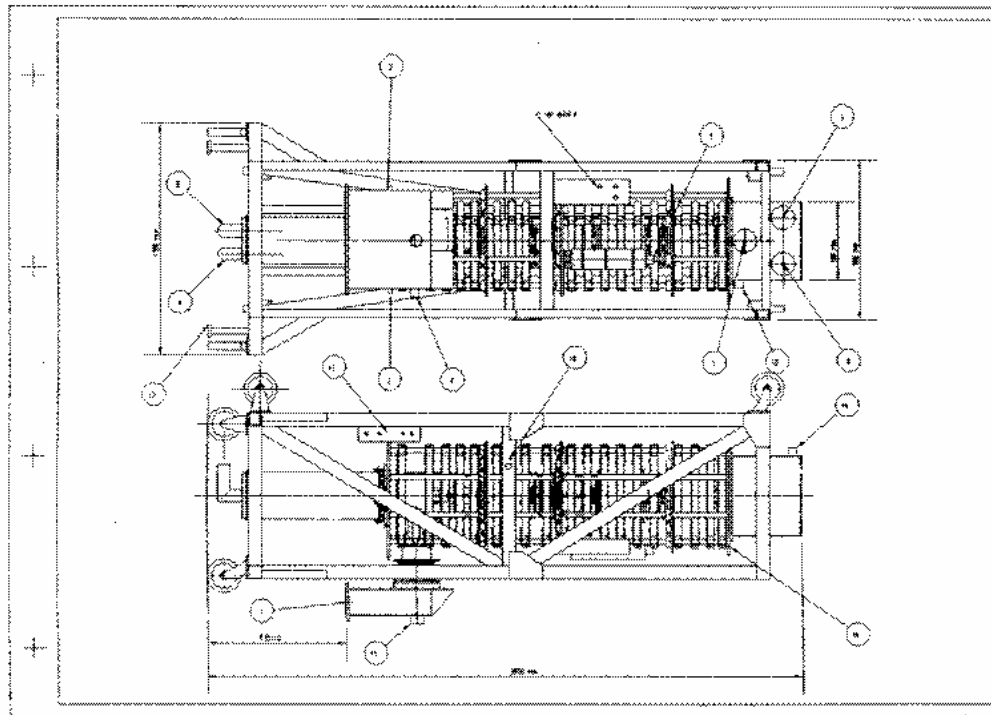
LHC Klystrons – Review & Basic Characteristics



LHC Klystron TH 2167

SBU Tubes of Disposal: Hyperfrequencies

RCD TH 2167



DISPOSALITY TECH/COMMUNIC/DEL/ES/HADEL/PH/13/102

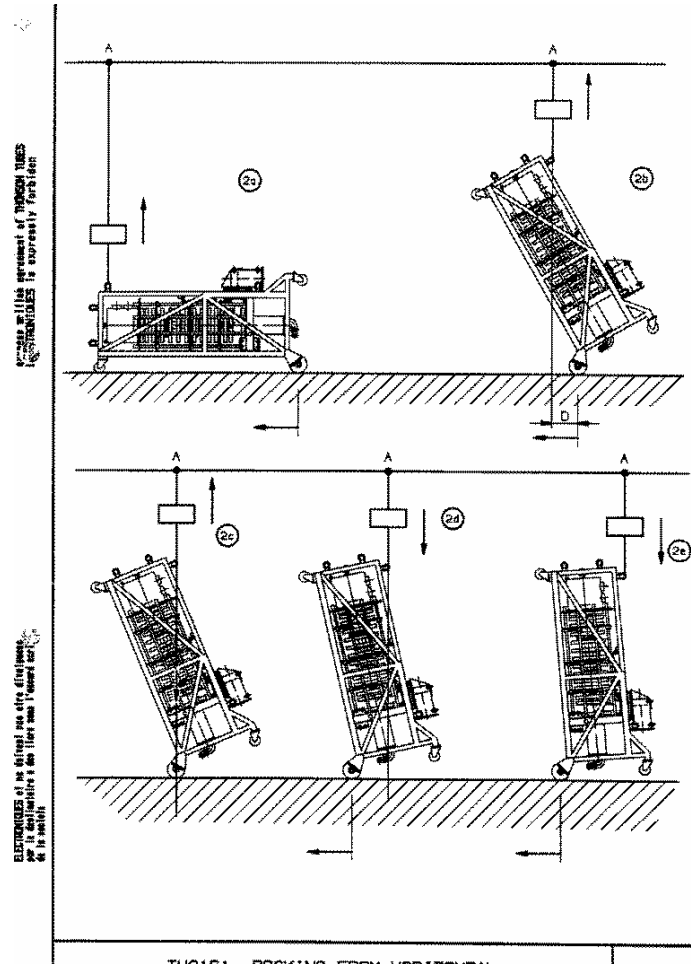
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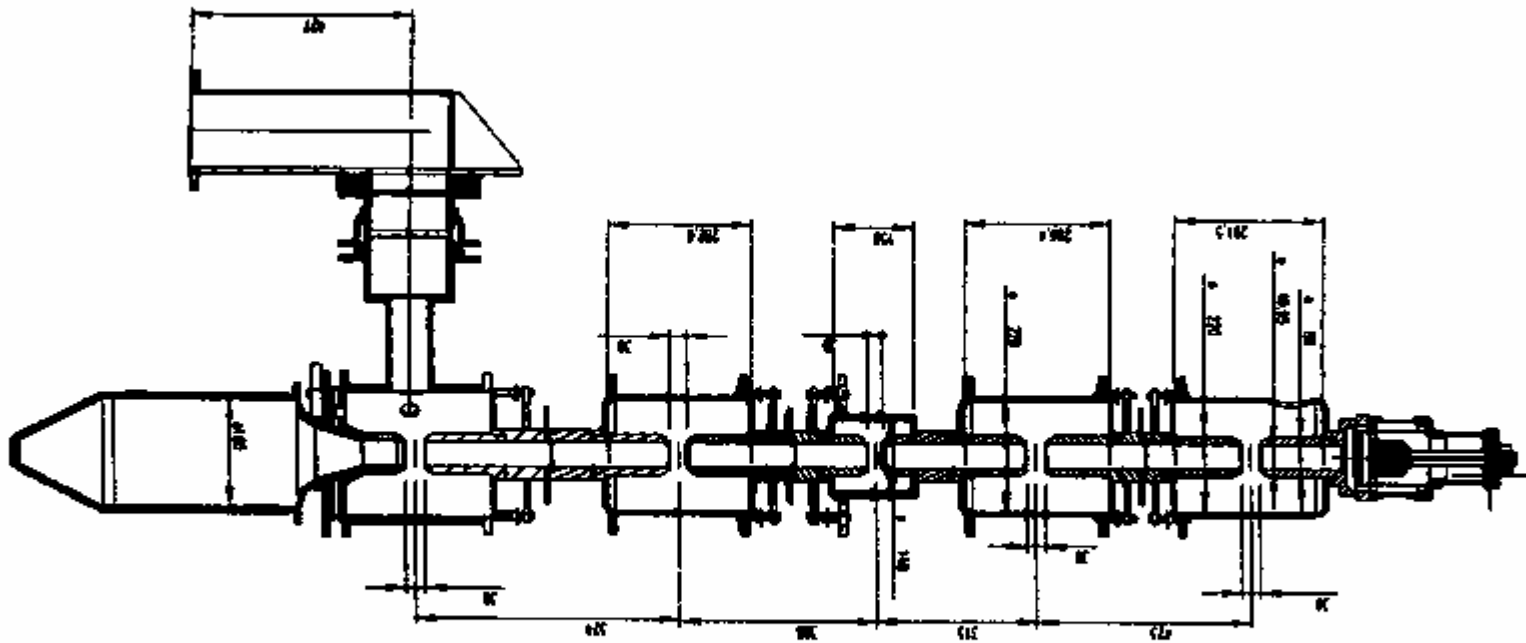
THALES

LHC Klystrons

- 20 Ordered: 16 plus 4 spares
- Some Features
 - Modulating Anode to vary beam current
 - Air cooled gun (not oil as LEP klystrons)
 - Filament and cathode at High Voltage
 - Operating HV levels 46, 50 & 54 kV
 - Ion pump → 8l/sec
 - Crossbar transition to waveguide
- Characteristics
 - Operating frequency 400 MHz
 - Power rating 300 kW
 - VSWR < 1.2
 - Group delay < 250 nS
 - Mod Anode current < 2.5 mA
 - Gain 37 dB
 - 2nd & 3rd harmonic output power better than 30 dB down on fundamental

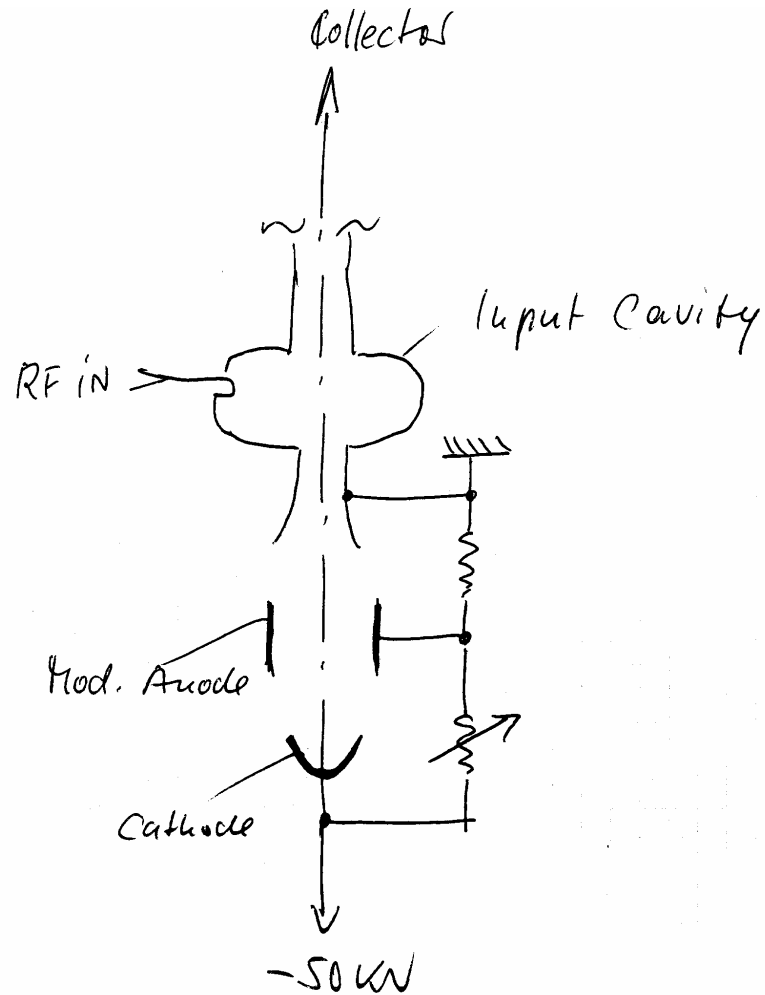
Horizontal to Vertical Positioning







Mod Anode Connection



4.4.1 Electrical parameters

Rated output power	300 kW _{cw}
Operating frequency (f_0)	400.8 MHz
-1dB Bandwidth (Operation 1dB below Saturated Output at each Working Point, see Table 3.	$\geq \pm 1$ MHz
Gun Perveance ($pg = I_b \cdot U_{ba}^{-1.5}$) @ $U_b=50$ kV and $I_b=8$ A	$1.5 \cdot 10^{-6} (A \cdot V^{-1.5})$ -0%+10%
Load VSWR @ any RF Phase	≤ 1.2
Beam voltage (U_b) @ Rated Output Power	≤ 54 kV
Beam Current (I_b) @ Rated Output Power	≤ 9 A
Cathode-to-Mod. Anode Voltage (U_{ba}) @ Rated Output Power	≤ 35 kV (see 4.4.3 1))
Modulation Anode Current (I_{am}) @ Rated Output Power	$\leq \pm 2.5$ mA
Saturated Gain @ all Working Points	≥ 37 dB
Group Delay within frequency range $f_0 \pm 0.25$ MHz and operation @ 1 dB below saturated Output (All Working Points)	≤ 250 ns
DC-to-RF Conversion Efficiency @ Saturated Output Power and Load VSWR ≤ 1.1	See Table 3
RF Test Power (to be generated for at least 1 hour during acceptance tests)	330 kW _{cw}
Beam Voltage @ RF Test Power	≤ 58 kV
Beam Current @ RF Test Power	≤ 10 A
Harmonic Content in Output Signal (measured @ rated output power and an output termination consisting of a waveguide load with a return loss of ≤ -26 dB at all possible propagating modes in the frequency range 400 to 1200MHz: @ 2nd Harmonic @ 3rd Harmonic	≤ -30 dB ≤ -30 dB
Signal Ratio of fundamental to other discrete frequencies within bandwidth and ≤ 80 to 100% of saturated Output Power (all working points)	≥ 60 dB
RF Phase Variation over Beam Current @ constant Beam Voltage and RF Drive Signal	$\leq 15^\circ/A$
RF Phase over Beam Voltage Variation @ constant Beam Current and RF Drive Signal (1 dB below saturated Output)	$\leq 10^\circ/\%$

Specified Parameters (1)

Specified Parameters (2)

	conductivity $\leq 5 \mu\text{S/cm}$
Nominal Water Temperature	$25 \pm 2^\circ\text{C}$
Cooling Water Connectors: Collector Body	SANDVIK, Type 48.3 $\times$ 2.6, 316L, WALTHER Quick Connector Type DN12
Cooling Water Flows: Collector Body	$\leq 500 \text{ l/min}$ $\leq 12 \text{ l/min}$
Cooling Water Pressure Drops: Collector Body	$\leq 3 \text{ bars}$ $\leq 3 \text{ bars}$
Test Pressure of Water Circuits	10 bars
Cooling of Output Window, HV Tank and Focusing Coils (connections, pressures and flows to be specified by manufacturer)	Air cooled
Air Flow and Pressure Drop: HV Insulation Box	$\leq 1500 \text{ l/min},$ $\leq 20 \text{ mbars}$
Output Window	$\leq 1000 \text{ l/min},$ $\leq 60 \text{ mbars}$

Table 2

Working Point	U_b (kV)	I_b (A)	Beamperv. ($\mu\text{A/V}^{-1.5}$)	P_{DC} (kW)	Saturation efficiency	$P_{out \text{ sat.}}$ (kW cw)
I	46	7	0.71	322	≥ 0.62	≥ 200
II	50	8	0.72	400	≥ 0.63	≥ 250
III	54	9	0.72	486	≥ 0.62	≥ 300

Table 3

Specified Parameters (3)

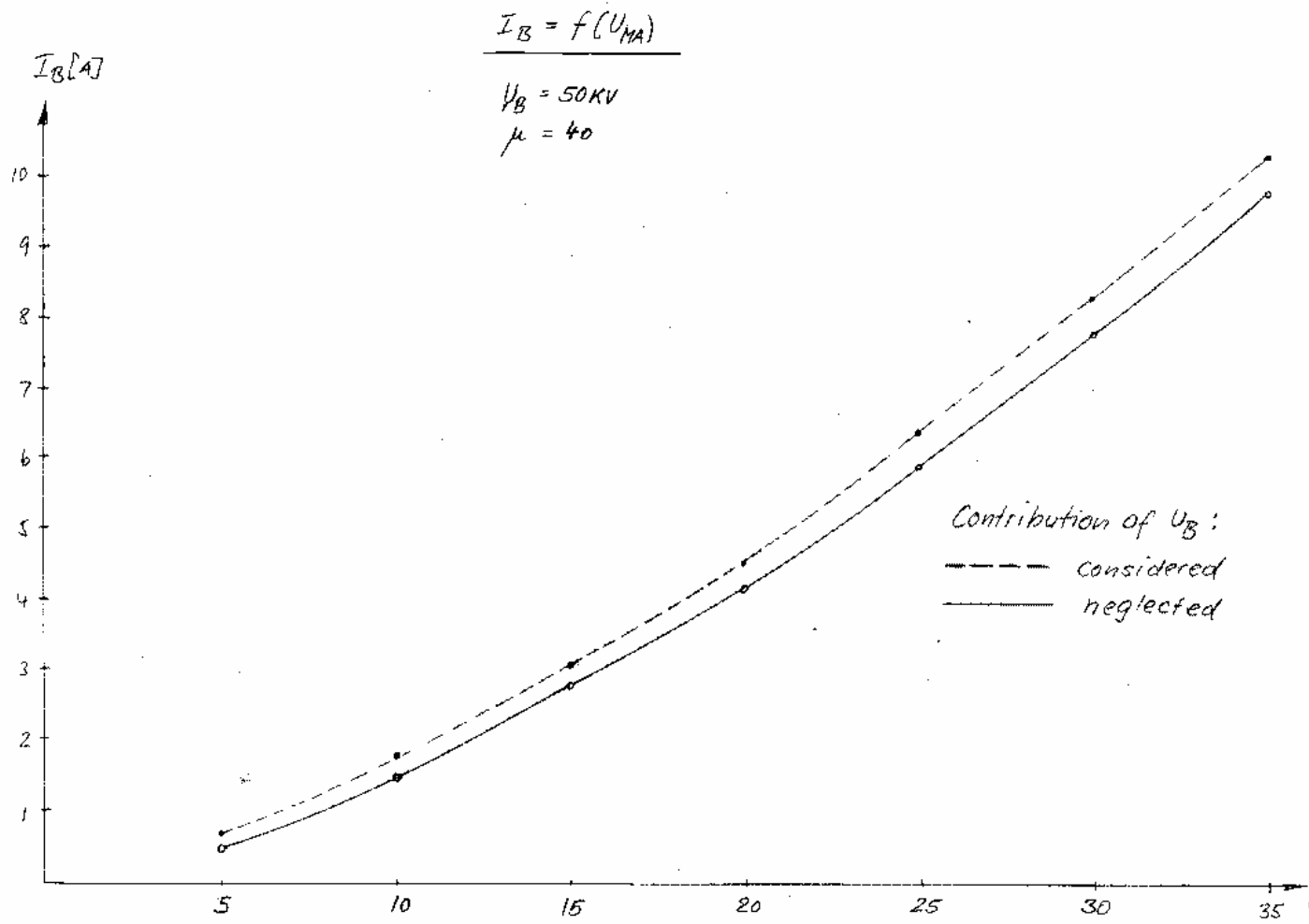
RF Output Power over Beam Voltage Variation @ constant Beam Current and RF Drive Signal (1 dB below saturated Output)	≤ 0.1 dB/%
Body Dissipation (under all possible operating conditions)	≤ 10 kW (see 4.4.3 1))
Continuous Collector Dissipation Capability (with or without RF Drive)	≥ 500 kW
Cathode Heater:	
Voltage	≤ 30 Vac
Current	≤ 30 Aac (see 4.4.3 2))
Ion Pump Voltage	≥ 5 kV (See 4.4.3 3))
RF Radiation from any Surface @ Test Power	≤ 0.1 mW/cm ²
Magnetic Field 1 m from Klystron Axis	≤ 0.5 mT
DC Test Voltages (cold cathode):	
Cathode/Modulation Anode to Ground	≥ 70 kV for 15 min
Cathode to Modulation Anode	≥ 60 kV for 15 min

Table 1

4.4.2 General parameters

Transport and operating positions	horizontal and vertical
Maximum overall dimensions of complete assembly	see 4.4.3 4)
Support for horizontal and vertical klystron position	see 4.4.3 5)
Tipping Device	see 4.4.3 6)
Maximum X-radiation at any klystron surface	5 μ Sv/h see 4.4.3 7)
HV connectors for cathode, heater and modulation anode	see 4.4.3 8)
RF Input Connector	Type N, 50 Ω , female
RF output connector	Half-height WR 2300 flange see 4.4.3 9)
Ion Pump Connector	LEMO, Type ERA.3S.415.TPA
Focusing Coil Connector	SOCAPEX, Type SL/EM 22B
Cooling Water	Deminerlized Water,

Mod Anode Characteristic



Some Explanations: 1

Perveance

1) Diode: $p = \frac{I_b}{U_b^{3/2}}$

$p = \text{constant}$, depends only on geometry of gun

2) Triode:

a) gun perv. $p_g = \frac{I_b}{(U_{HA} + \frac{U_b}{\mu})^{3/2}}$

LEP Klystrons: $\mu = 35 \dots 40$

LEP/LHC Klystrons: $p_g \approx 1.5 \cdot 10^{-6} [A \cdot V^{-3/2}]$
(@ rated output)

b) beam perv.

Jackim's Addendum:

$$p_b = p_g \left(\frac{U_{HA}}{U_b} + \frac{1}{\mu} \right)^{3/2}$$

$$p_b = \frac{I_b}{U_b^{3/2}} [A \cdot V^{-3/2}]$$

↓

Variable = $f(U_{HA})$

LEP/LHC Klystrons:

$$p_b \approx 0.7 \cdot 10^{-6} [A \cdot V^{-3/2}]$$

(@ rated output)

Some Explanations: 2

Efficiency (empirical)

$$\eta \approx 0.78 - 0.16 \cdot \mu p$$

e.g. @ $\mu p = 0.7 \rightarrow \eta \approx 66\%$

Output Power $P_{RF} = f(U_b)$

$$P_{RF} = \eta \cdot U_b \cdot I_b$$

$$P_{RF} = \eta \cdot p_b \cdot U_b^{5/2}$$

$\Delta U_b \ll U_b : \Delta U_{RF} \sim \Delta U_b^{5/4}$

⚡ 1% ripple on $U_b \rightarrow$ 1.2% ripple on U_{RF}

$$\frac{\Delta U_{RF}}{\Delta U_b} = 1.2 \% / \% \quad (0.1 \text{ dB})$$

Output Phase ($\phi = f(U_b)$)

$$\sigma = 1 + \frac{U_b(\text{kV})}{512}, \quad \sigma = \frac{1}{\sqrt{1 - \left(\frac{v}{c}\right)^2}}$$

$U_b = 50 \text{ kV} : \sigma = 0.4123 \cdot c$

interaction length: $1.648 \text{ m} \rightarrow t = 13 \text{ ns}$

⚡ 1% ripple on $U_b \rightarrow \Delta \phi_{RF} = 8.4^\circ$

$$\frac{\Delta \phi_{RF}}{\Delta U_b} = 8.4 \% / \%$$

$U_b : 25 \text{ kV} \dots 50 \text{ kV} \rightarrow \Delta \phi_{RF} = 706^\circ$

Some Explanations: 3

Test Power: $P_{\text{test}} : 330 \text{ kW}$

$P_f : 300 \text{ kW}$
 $P_r : 360 \text{ W}$ } Joachim
(seen by circulator)

$$P_e = \frac{1}{4} (\sqrt{P_f} + \sqrt{P_r})^2 = 330 \text{ kW}$$

Measurements on LEP Klystrons (1)

- 5 -

Points 4-5

Fréquence RF: 352.21 MHz

Puissance d'entrée = 59... W

U_{MA} = 67... kV

U_k	Phase °	P. sortie (coupleur)	I cath.	I_{MA}
kV		kW	A	mA
87	0	1050	17.9	0.2
86	+9	1036	17.9	0.2
85	+20	1022	17.9	0.2
84	+30	994	17.9	0.2
83	+38	965	17.9	0.2
82	+48	936	17.9	0.3
81	+50	922	17.9	0.3

$$\frac{U_{max} - U_{min}}{U_{moy}} = 7.1... \%$$

$$\boxed{8.4 \text{ } \circ/\%$$

(max: 15° %)

$$\boxed{-0.08 \text{ dB}/\%$$

(max: 0.2 dB %)

Remarques:

(Thomson TH 2089)

Measurements on LEP Klystrons (2)

- 6 -

Points 4-5

Fréquence RF: 352.21 MHz

Puissance d'entrée = 90 W

U_{MA} = 47 kV *60*

U_k	Phase $^\circ$	P. sortie (coupleur)	I cath.	I_{MA}
kV		kW	A	mA
90	0	1004	16.7	0.5
89	-7	994	"	0.5
88	-15	984	"	0.5
87	-21	966	"	0.5
86	-30	949	"	0.4
85	-38	933	"	0.2
84	-44	912	"	0.2
.....				
.....				
.....				

$$\frac{U_{\max} - U_{\min}}{U_{\text{moy}}} = 6.9 \%$$

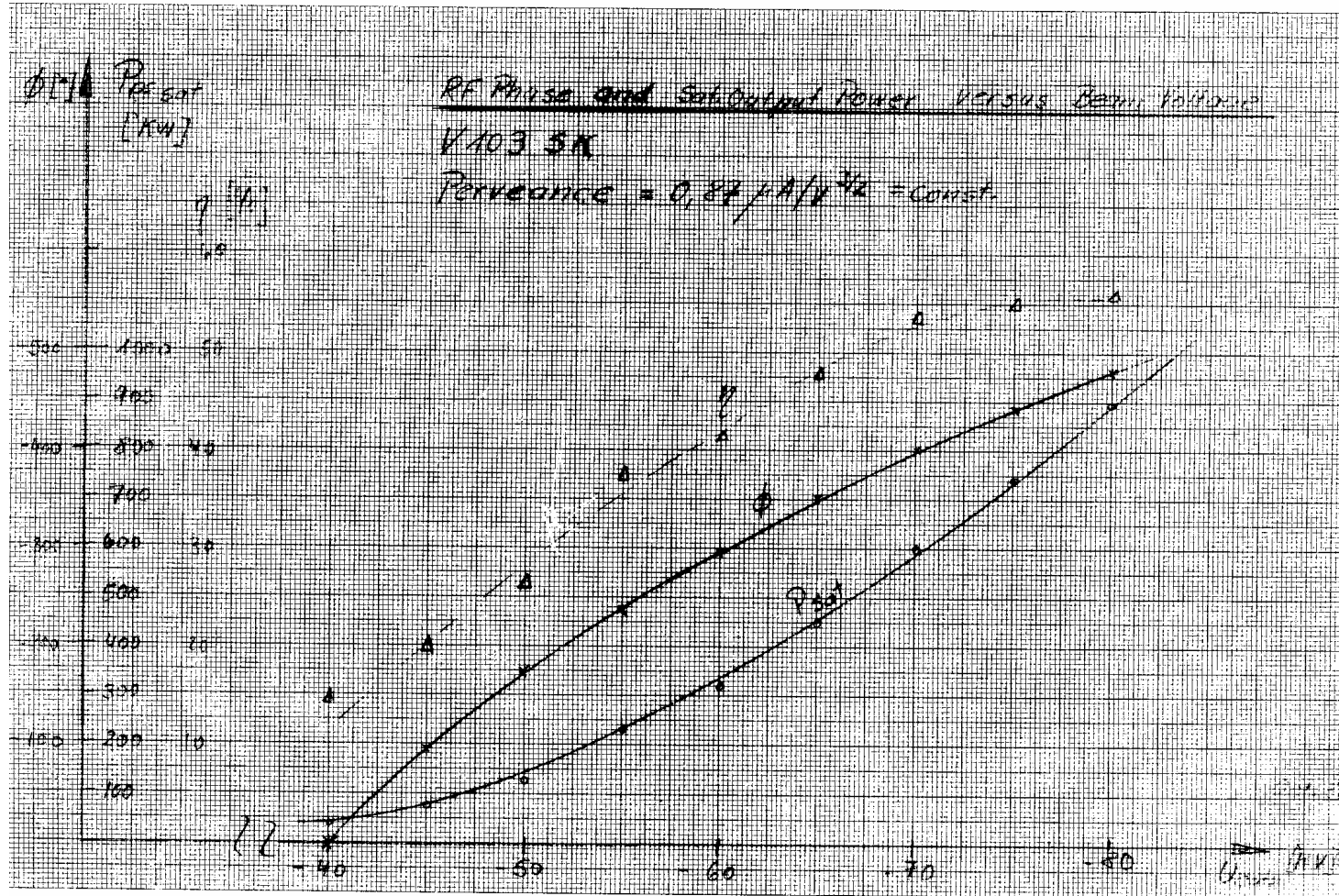
$$\boxed{6.4 \%} \quad (\text{max: } 15 \%)$$

$$\boxed{-0.08 \text{ dB} \%} \quad (\text{max: } 0.2 \text{ dB} \%)$$

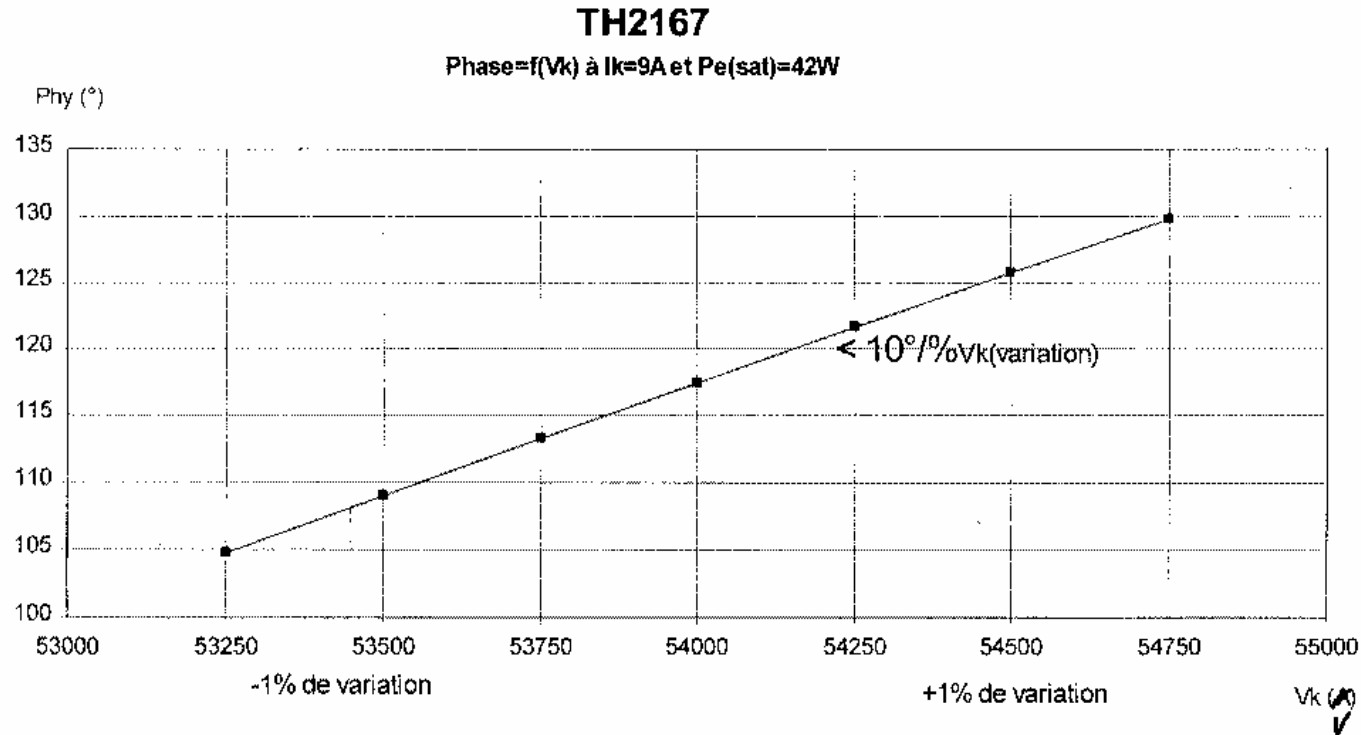
Remarques:

(Philips YK1350)

RF output Power & Phase vs. DC Voltage – LEP Klystron



RF Phase vs. DC Voltage – LHC Klystron

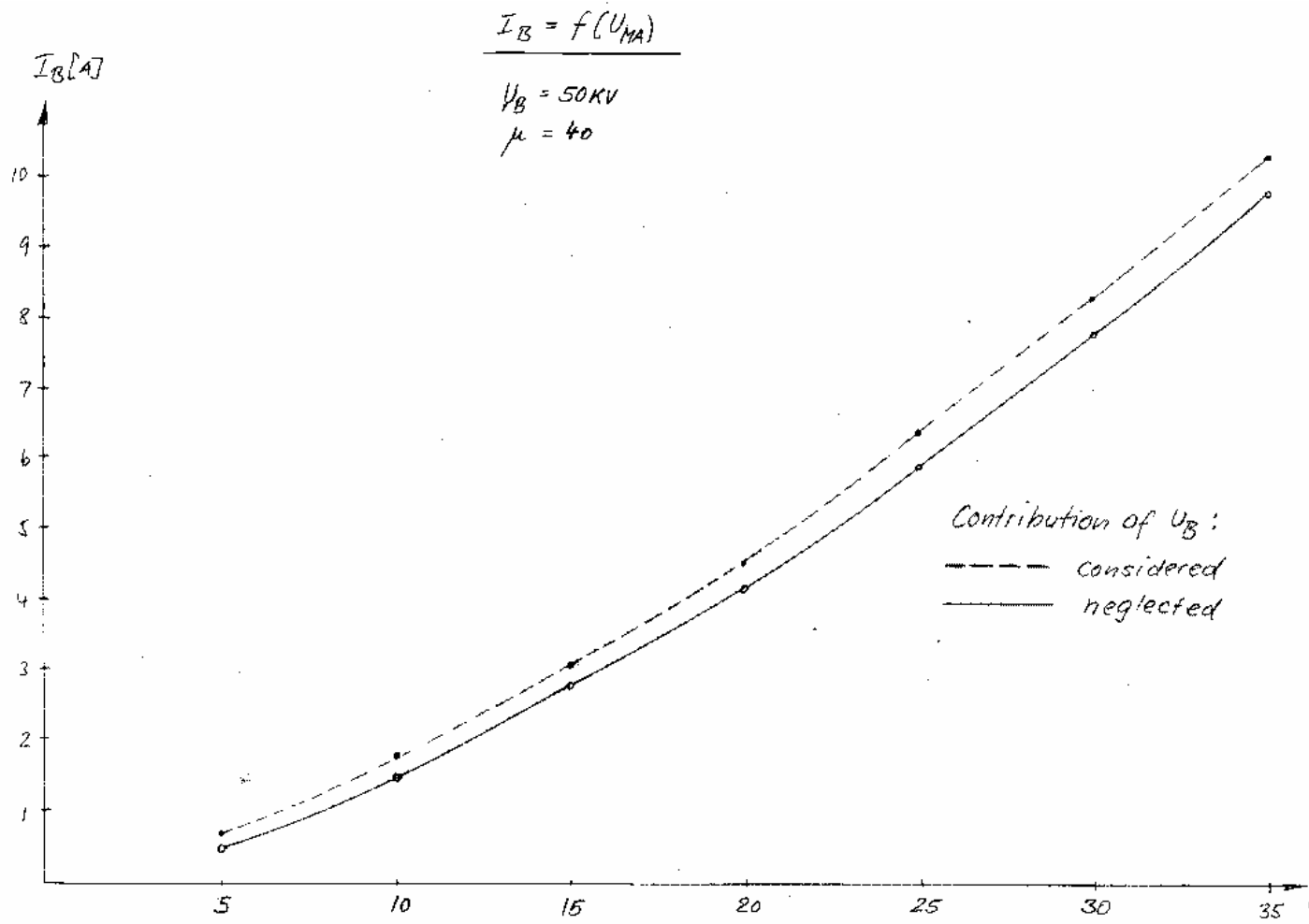


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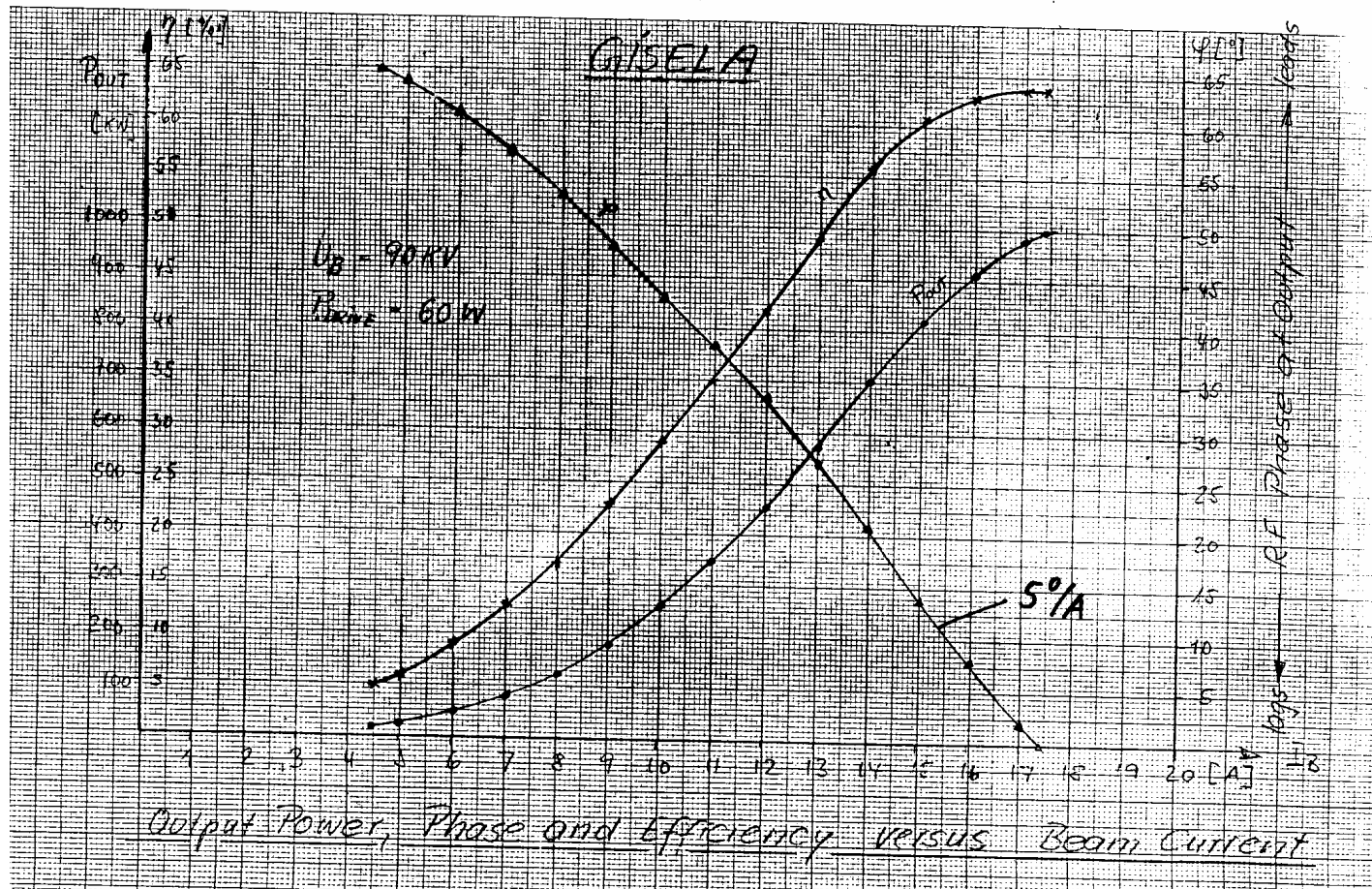
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Mod Anode Characteristic



RF output Power, Phase & Efficiency vs Beam Current – LEP Klystron



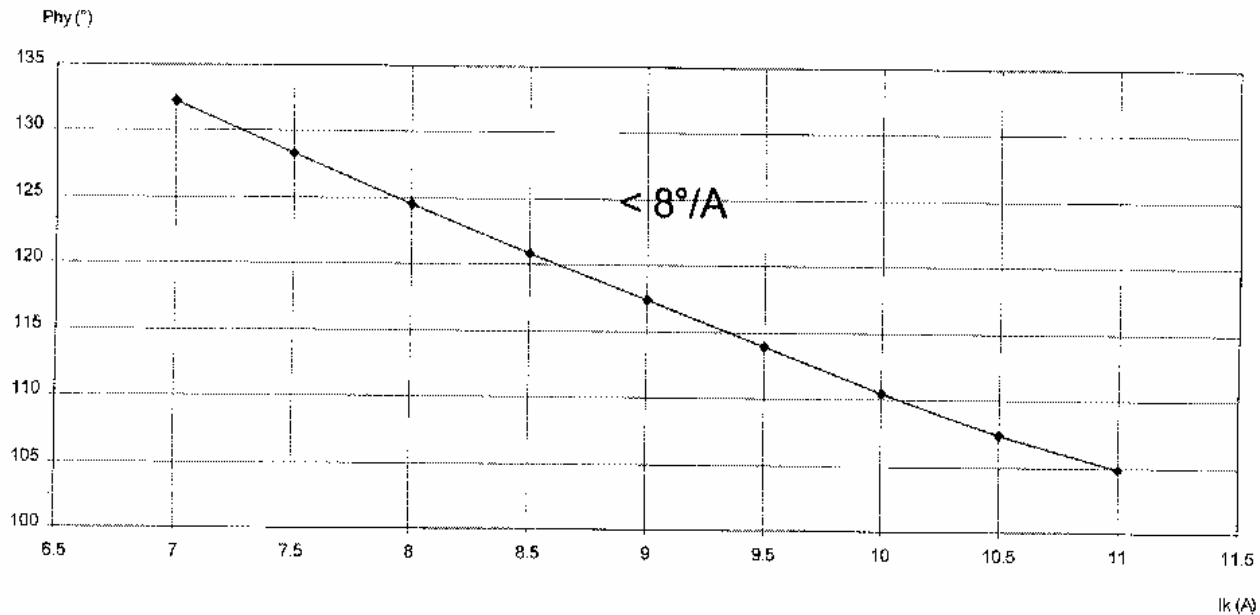
RF Phase vs. Beam Current – LHC Klystron

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TH2167

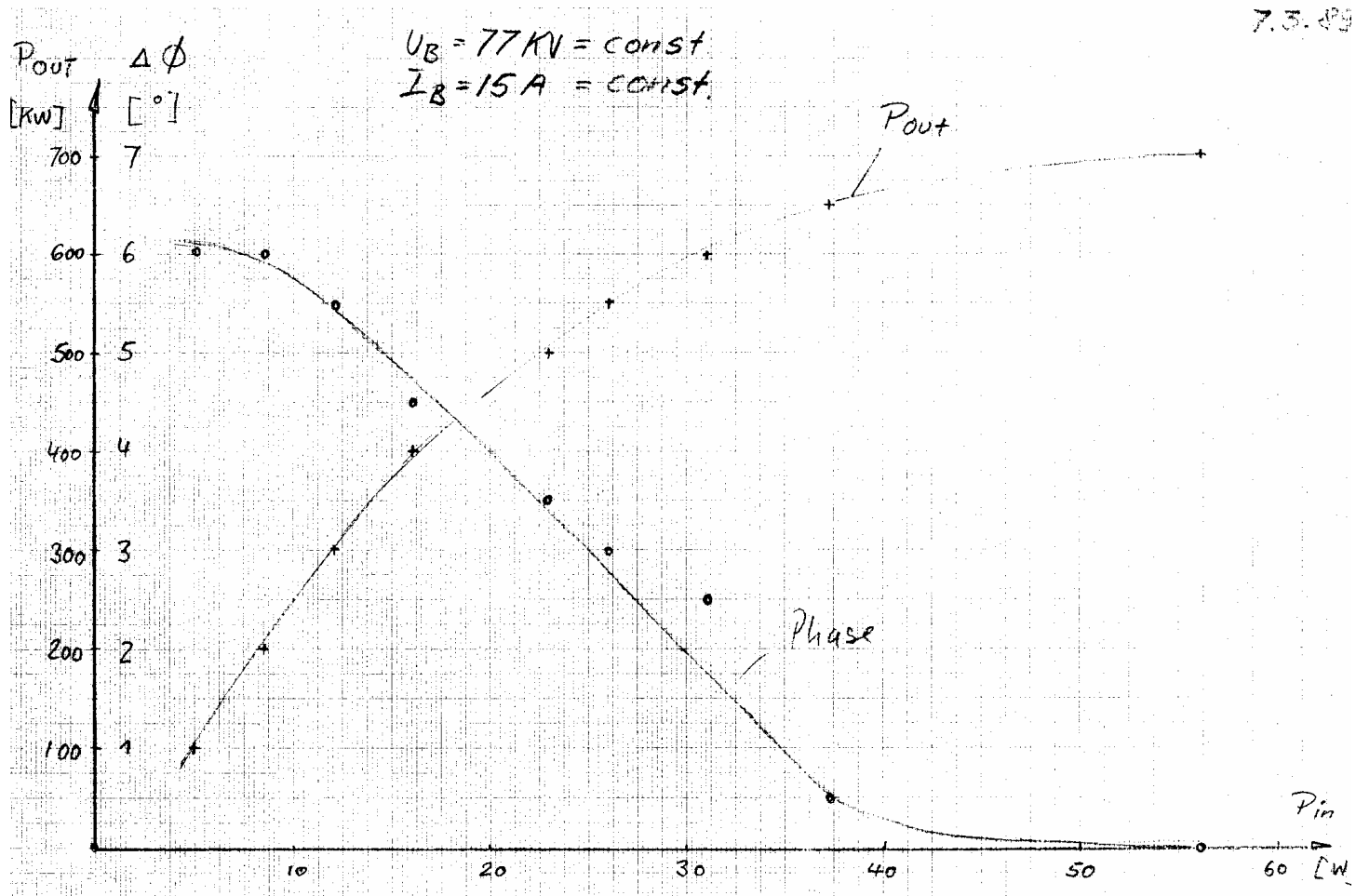
Phase=f(Ik) à $V_k=54\text{kV}$ et $P_{e(\text{sat})}=42\text{W}$



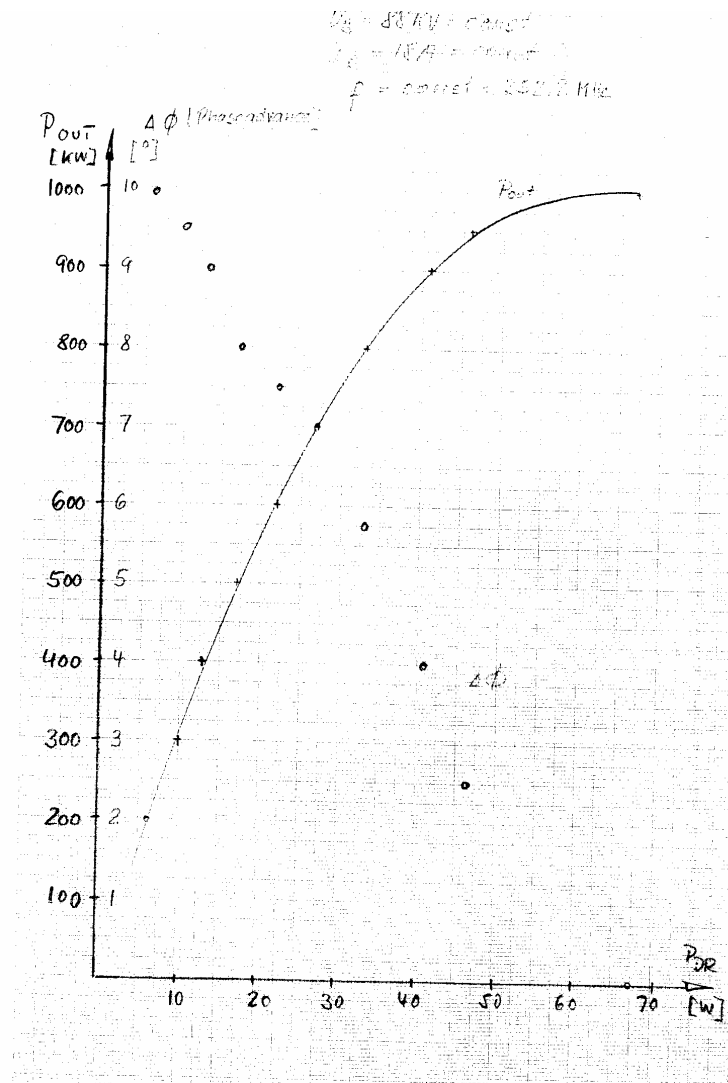
THALES ELECTRON DEVICES

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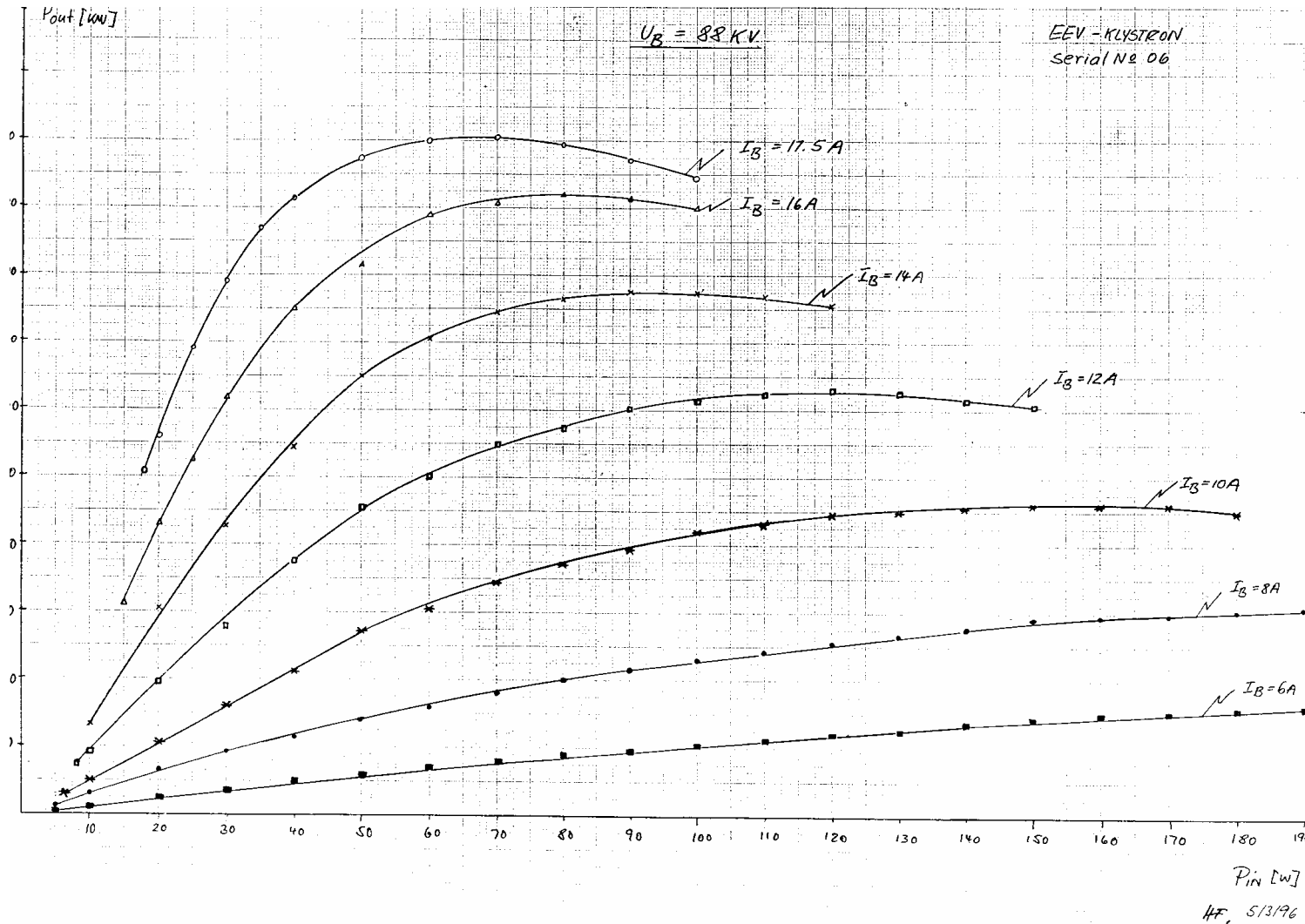
RF Output Power & Phase Vs. Input Power – LEP Klystron



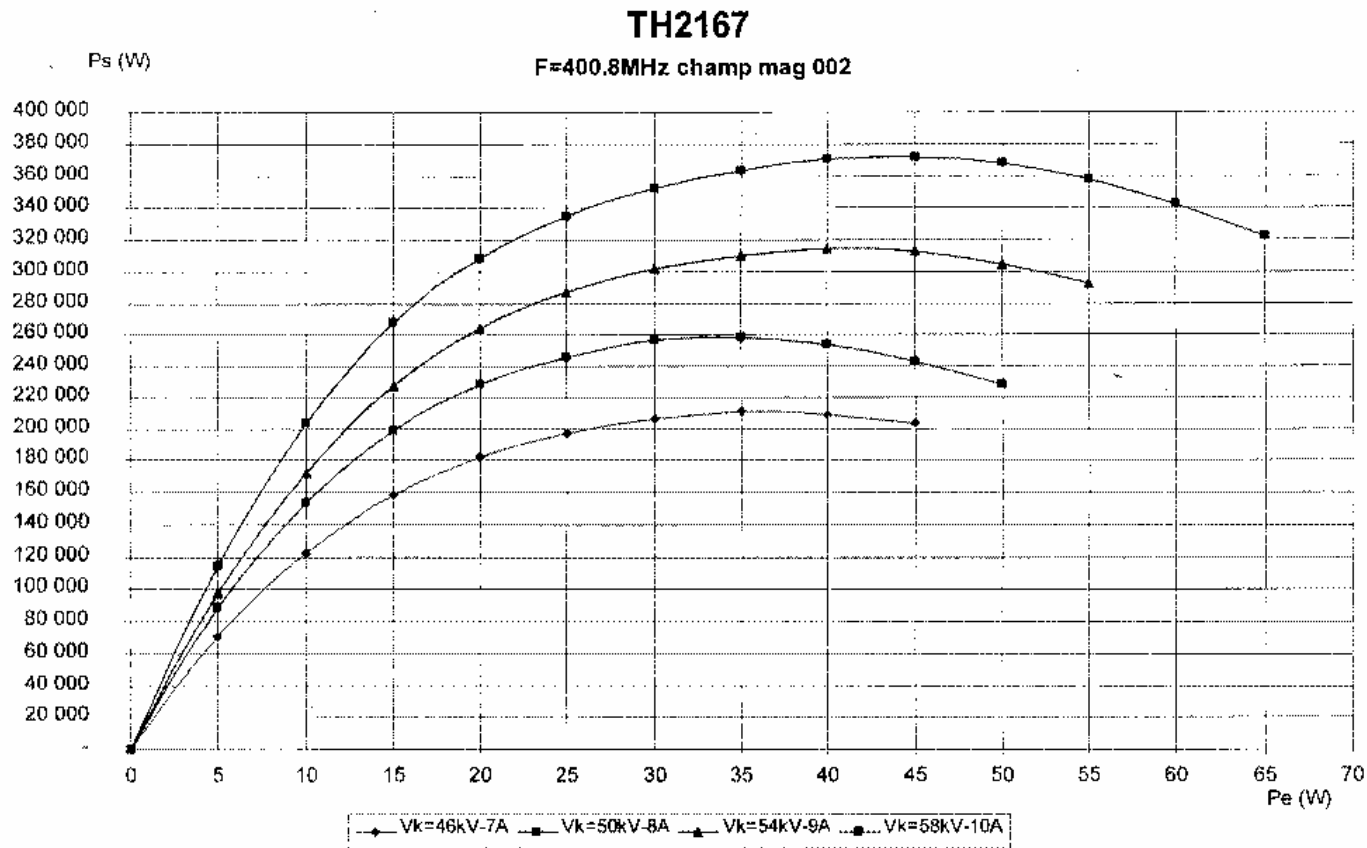
RF Output Power & Phase vs. Input Power – LEP Klystron



RF Output Power & Phase vs. Input Power, Various I_b – LEP Klystron



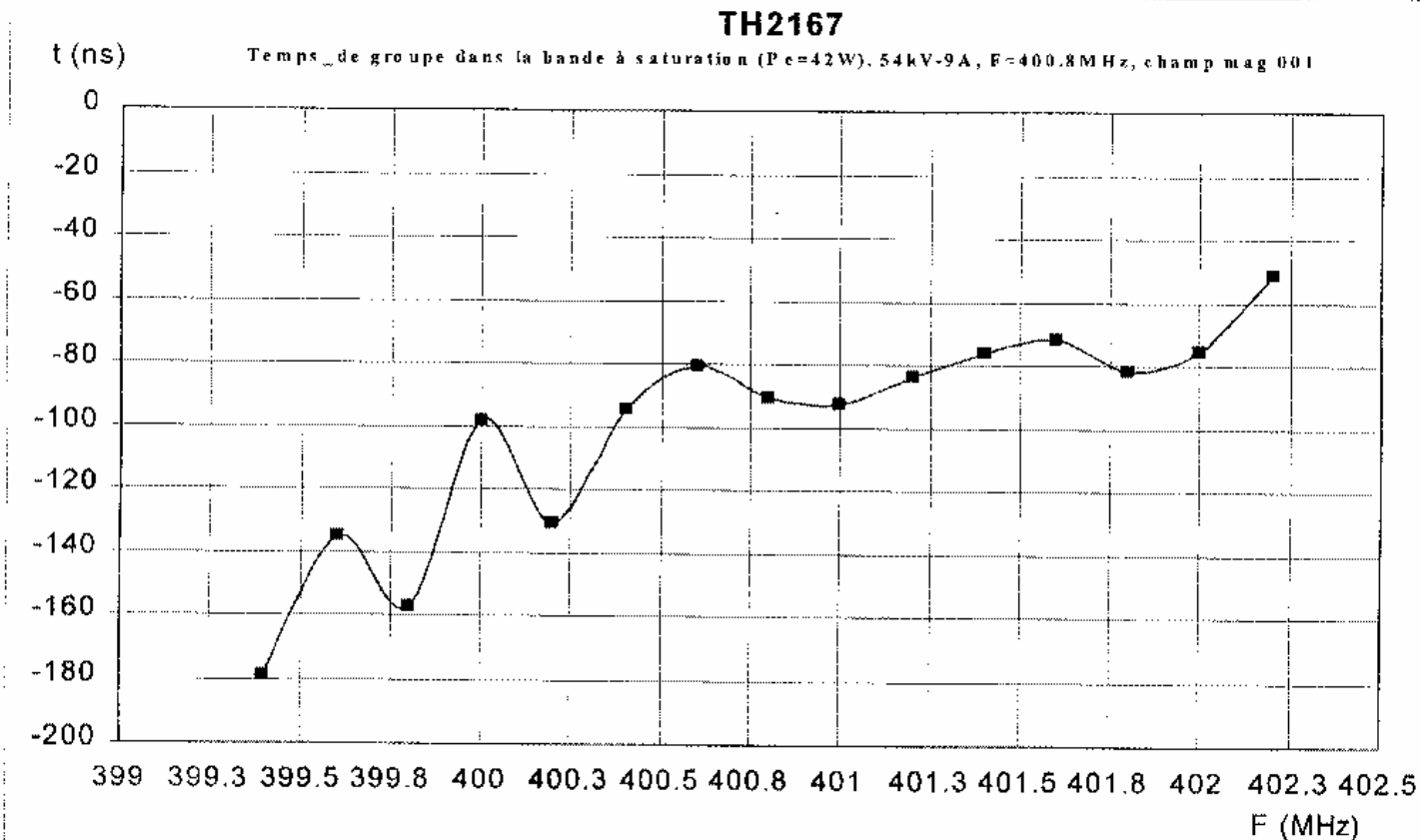
RF Output Power vs. Input Power, Various DC Voltage/ I_b – LHC Klystron



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Group Delay vs. Frequency – LHC Klystron



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Group Delay vs. Frequency – Drive Amplifier

